

SANYO**LA6564H****4CH Bridge (BTL) Driver for CD-R****Overview**

The LA6564H is a 4-channel BTL driver developed for CD-ROM/R/RW and DVD-ROM actuator.

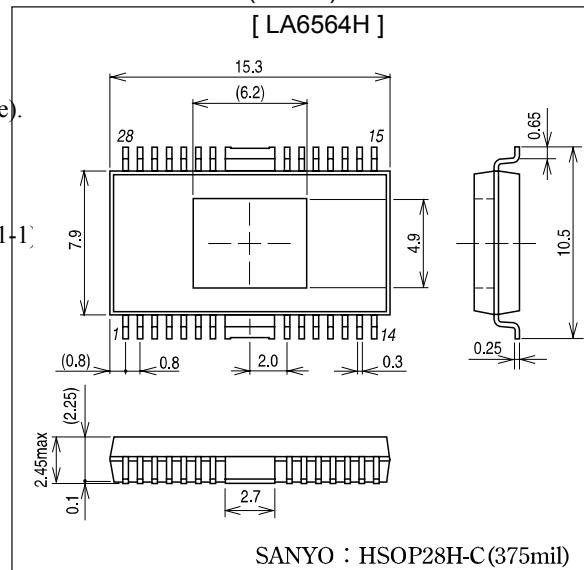
Functions

- Three power supply systems (with a separate preamplifier stage).
- Four bridge-connection (BTL) power amps built-in.
- I_O max : 1A.
- Mute circuit (output ON/OFF) built-in. With three systems (2-1-1).
- Provides output voltage setting pin (for 4CH only).

Package Dimensions

unit : mm

3234A-HSOP28H-C (375mil)



SANYO : HSOP28H-C(375mil)

Specifications**Maximum Ratings at $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V_{CC} max	*1	14	V
Supply voltage 2	VS max	*1	14	V
Allowable power dissipation	P_d max	Independent IC	0.82	W
		A specified substrate (114.3mm×76.1mm×1.6mm/glass epoxy)	2	W
Maximum input voltage	V_{INB}		13	V
Mute pin voltage	$VMUTE$		13	V
Maximum output current	I_O max	Each output	1	A
Operating temperature	$Topr$		-30 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

1 Note : $V_{CC} \geq VS^$

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LA6564H

Recommended Operating Conditions at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V_{CC}	V_{CC} *1	4 to 13.5	V
Supply voltage 2	VS	VS 1,2,3 *1	4 to 13.5	V

1 Note : $V_{CC} \geq VS^$

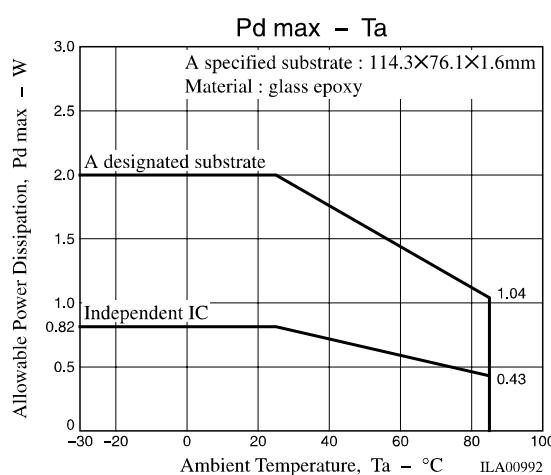
Electrical Characteristics at $T_a = 25^\circ\text{C}$, $V_{CC} = 12\text{V}$, $VS_1 = VS_2 = 5\text{V}$, $VS_3 = 12\text{V}$, $V_{REF} = 1.65\text{V}$, unless otherwise specified

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[All Blocks]						
V_{CC} no-load current drain	I_{CC-ON}	V_{CC} current, all outputs ON (all MUTE : H)		20	30	mA
No-load current drain OFF	I_{CC-OFF}	Total current of V_{CC} and VS_1 through 3 (All MUTE : L)			0.5	mA
[Output AMP Block]						
Output offset voltage	V_{OFF}	Between + and - outputs of each CH	-50		50	mV
Output voltage 1	V_{O1}	$R_L = 8\Omega$, voltage between outputs of CH1 through CH3 *1	4	4.5		V
Output voltage 2	V_{O2}	$R_L = 16\Omega$, voltage between outputs of CH4 *1	10.5	11		V
Closed-circuit voltage gain 1	VG_1	CH1,2,3, input and output gain	10	12	14	dB
Closed-circuit voltage gain 2	VG_2	CH4, input and output gain	16	18	20	B
Input voltage range	V_{IN}	Each input pin	0		VS^*	V
Slew rate	SR	Independent AMP. Doubled when between outputs.		0.5		V/ μ s
[MUTE Block]						
MUTE ON voltage	$VMUTE-ON$	MUTE *2	2			V
MUTE OFF voltage	$VMUTE-OFF$	MUTE *2			0.5	V
MUTE pin inrush current	$I-MUTE$	Inrush current of each MUTE pin		25	50	μ A
[AREF AMP Block]						
V _{REF-IN} input voltage range			1		$V_{CC}-1.5$	V
[Voltage limiter block] [Setting the limit value of CH4 output voltage]						
V_O-SET input and output gain	$G-V_O-SET$	*1	11	12	13	dB
V_O-SET input current	$I-V_O-SET$	V_O-SET : current at 3.3 V			1	μ A

*1. Output saturated.

*2. MUTE output ON with HI and OFF with LOW (High impedance with AMP output OFF).

MUTE operates independently for each CH (Refer to "Relationship of MUTE and output" described later).



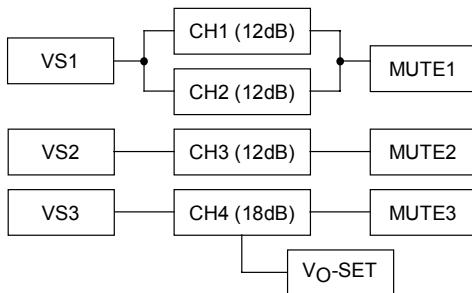
1) Relationship of MUTE and output

	Output			
	CH1	CH2	CH3	CH4
Each MUTE	MUTE1		MUTE2	MUTE3
H		ON		
L		OFF		

*1 The output becomes HI impedance when it is OFF.

*2 MUTE operates independently for each CH (Refer to the following description). All MUTES enter the STBY mode when they are L (output OFF), turning OFF all the circuits including the output AMP.

2) Relationship between each CH and V*, MUTE



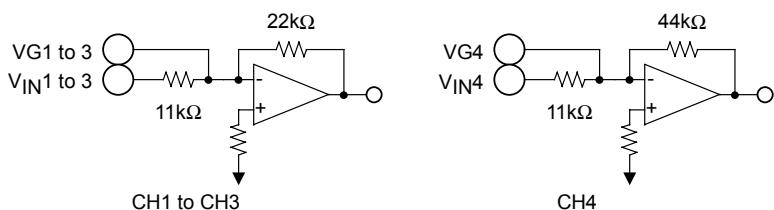
3) VO-SET

VO-SET operates for CH4. VO-SET is correlated to CH4 output by 12dB. For example, the output is 4V when VO-SET is 1V.

4) Gain set (VIN* and VG*)

Gain of each CH can be equivalently represented as follows :

- CH1 to CH3 : 12dB, CH4 : 18dB when only VIN pin is used. The similar gain is obtained also when a 11k resistor is used for the VG* pin and the input is provided from its resistor end.
- The input/output gain is determined from the resistance ratio as shown in the figure below. To set the gain with the VG pin, the input-output gain has a slight temperature characteristic depending on the difference in temperature characteristic between internal and external resistances.

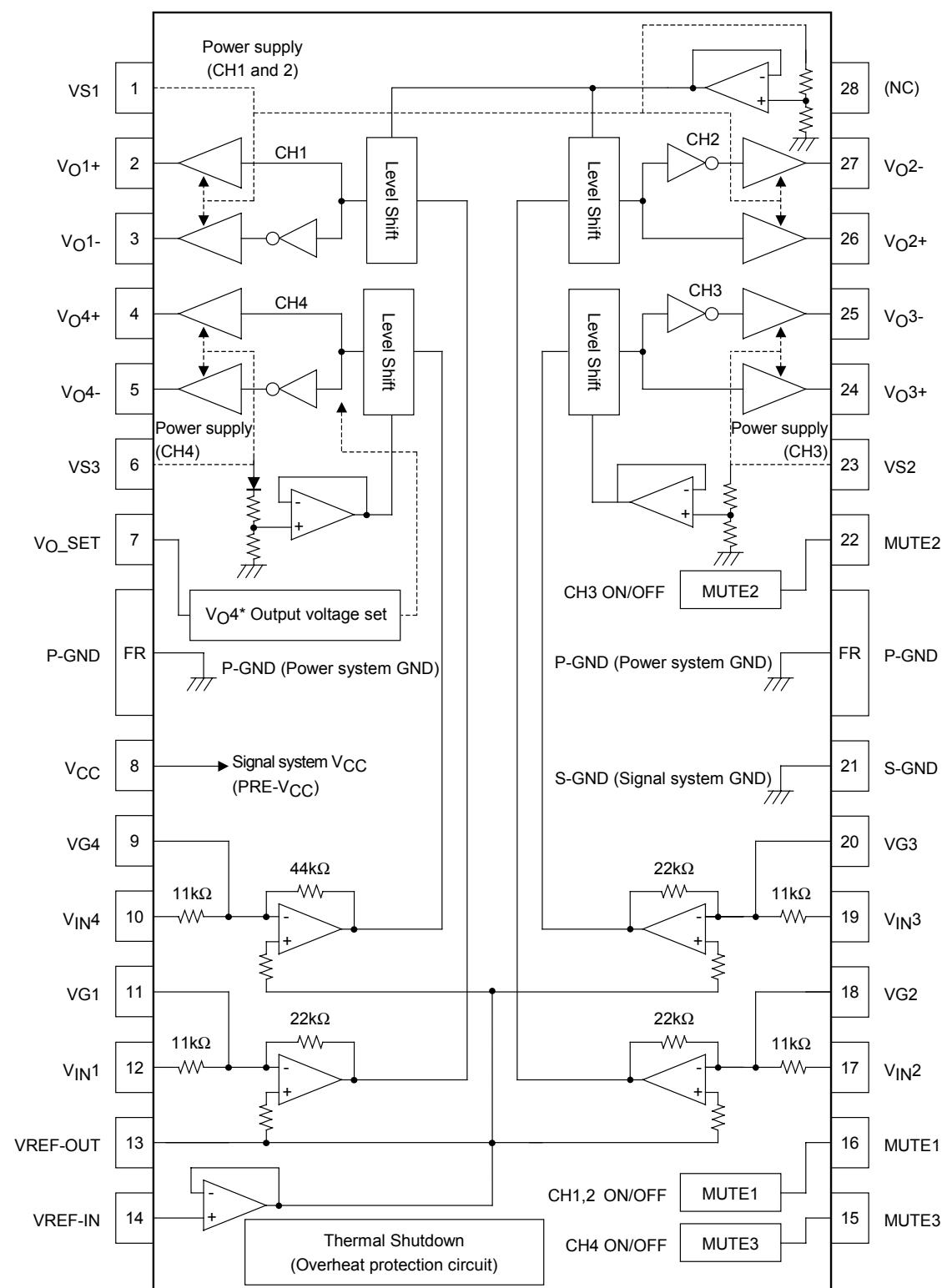


Pin Functions

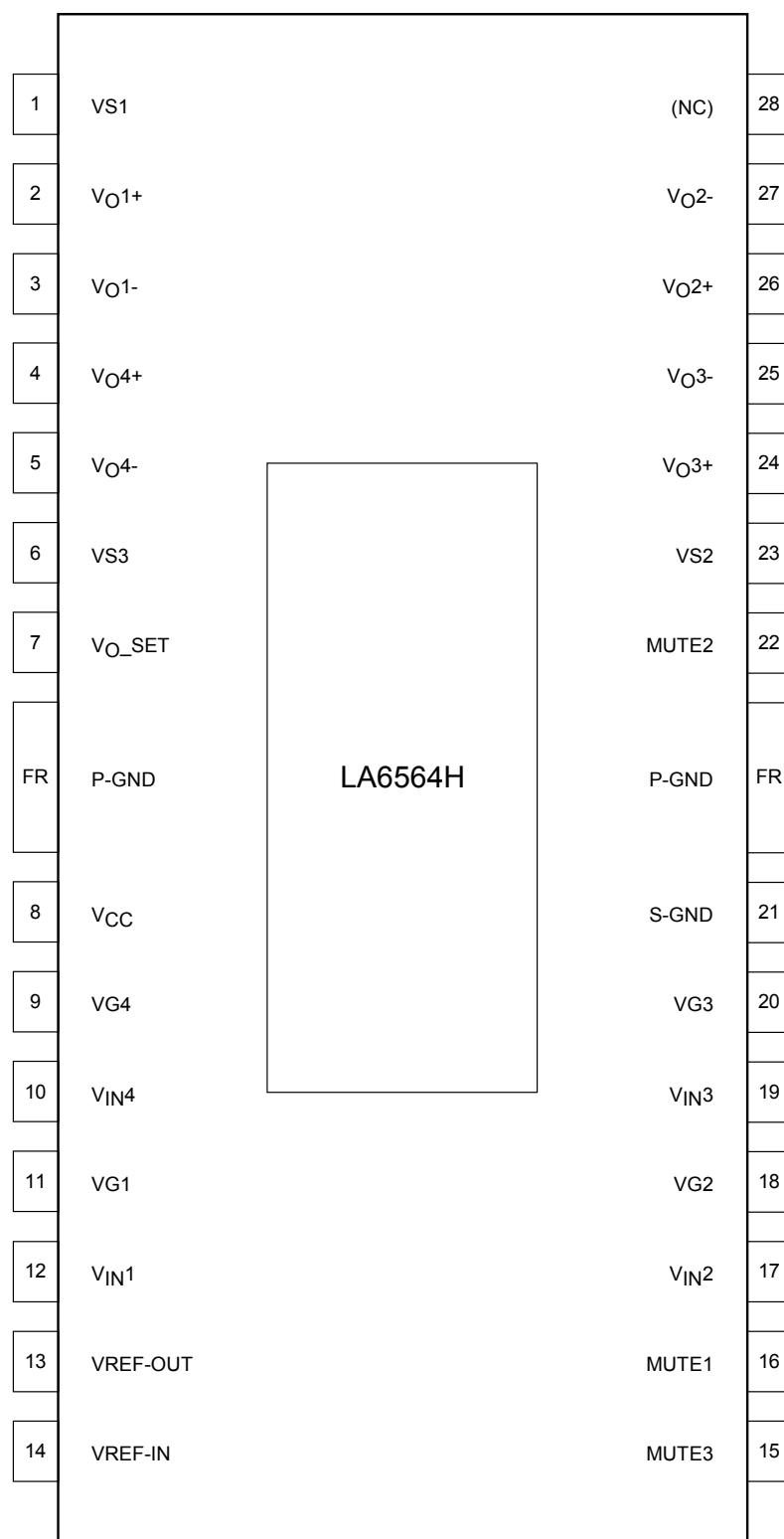
Pin No.	Pin Name	Description (Functions)
1	VS1	Output stage power supply for channel 1 and 2
2	V _O 1+	Output pin (+) for channel 1, non-inverted output for channel 1 input
3	V _O 1-	Output pin (-) for channel 1, inverted output for channel 1 input
4	V _O 4+	Output pin (+) for channel 4, non-inverted output for channel 4 input
5	V _O 4-	Output pin (-) for channel 4, inverted output for channel 4 input
6	VS3	Output stage power supply for channel 4
7	V _O _SET	Pin to adjust channel 4 output voltage
8	V _{CC}	Power supply for preamplifier stage signal system
9	VG4	Input pin for channel 4 (for gain adjustment)
10	V _{IN} 4	Input pin for channel 4
11	VG1	Input pin for channel 1 (for gain adjustment)
12	V _{IN} 1	Input pin for channel 1
13	VREF-OUT	VREF-AMP output
14	VREF-IN	Reference voltage input pin
15	MUTE3	ON/OFF for channel 4 output
16	MUTE1	ON/OFF for channel 1 and 2 outputs
17	V _{IN} 2	Input pin for channel 2
18	VG2	Input pin for channel 2 (for gain adjustment)
19	V _{IN} 3	Input pin for channel 3
20	VG3	Input pin for channel 3 (for gain adjustment)
21	S-GND	Signal system GND
22	MUTE2	ON/OFF for channel 3 output
23	VS2	Output stage power supply for channel 3
24	V _O 3+	Output pin (+) for channel 3, non-inverted output for channel 3 input
25	V _O 3-	Output pin (-) for channel 3, inverted output for channel 3 input
26	V _O 2+	Output pin (+) for channel 2, non-inverted output for channel 2 input
27	V _O 2-	Output pin (-) for channel 2, inverted output for channel 2 input
28	(NC)	Do not use

* Center frame (FR) becomes GND for the power system (P-GND). Set this to the minimum potential together with S-GND.

Block Diagram



Pin Assignment



Top view

Pin Description

Name	Pin Name	Pin No.	Equivalent Circuit Diagram	Description
Input	V _{IN1} V _{IN2} V _{IN3} V _{IN4} VG1 VG2 VG3 VG4	12 17 19 10 11 18 20 9		Input pins
Output	V _{O1+} V _{O1-} V _{O2+} V _{O2-} V _{O3+} V _{O3-} V _{O4+} V _{O4-}	2 3 26 27 24 25 4 5		Output pins
MUTE	MUTE1 MUTE2 MUTE3	16 22 15		Switch for each channel output MUTE : H output ON MUTE : L output OFF

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